Physical and Optical Properties of Ge_{10}Se_{90-x}Sb_{x} Glasses

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ABSTRACT: Chalcogenides glasses doped with antimony (Sb) have shown remarkable potential in nonlinear and optoelectronic applications. In search of finding the optimised glass for the use in infra-red optics the new ternary Ge_{10}Se_{90-x}Sb_{x} (x = 0, 3, 6, 9, 12, 15, 18, 21, 24) system has been studied theoretically for variation in physical parameters. Transmission spectra for Ge_{10}Se_{90}Sb_{10} have been used to study the absorption and refractive index of the material. The compositional variation of Sb (Replacing Se) on the system has been studied in terms of average coordination number, cohesive energy, glass transition temperature and transmission spectra of the system.

KEYWORDS: Chalcogenide glasses, Glass transition temperature, Transmission spectra, Refractive index, Optical band gap.

I. INTRODUCTION

The elements in Group VI of periodic table S, Se, and Te along with more electropositive element such as Antimony (Sb) forms a special class of chalcogenide glasses. The phase change properties of chalcogenides make them attractive candidates to be used in all-optical devices [1]. Chalcogen glasses are generally less weakly bonded materials than oxide glasses. The alloy of Se-Sb improves the corrosion resistance and optical sensitivity of the alloy [2]. The addition of Ge and Sb with Se makes the material more promising glasses, having low transmission loss and high transparency to infrared radiations from 2 - 16 μm [3]. Ge-Se and Sb-Se glasses are promising materials for infrared optical fibres not only due to their high non-linearity and refractive index but also to their relatively good thermo-mechanical and chemical properties. The versatile behaviour of these materials makes us select this composition and study the effect of Sb in corporation in physical properties of Ge-Sb-Se glass. Physical interpretation and their results show Ge_{10}Se_{90-x}Sb_{x} (x = 0, 3, 6, 9, 12, 15, 18, 21, 24) as the most cross linked and stable. The addition of metallic impurity to glass alloy increases the conductivity and is very suitable for device fabrication [4].

II. MATERIALS AND METHODS

Thin films Ge_{10}Se_{90}Sb_{10} were deposited using thermal evaporation technique. The transmission spectra of these thin films were obtained using a double beam UV–VIS–NIR spectrophotometer. The slit width was kept at 1 nm and all the measurements were performed at room temperature (300K). The transmittance and reflectance measurements were carried out on a double beam spectrophotometer over a range 400 nm to 900 nm. Almost all the recording spectrophotometer uses a double beam principle and all achieve automatic control by suitable use of servomotors. In dual beam spectrophotometer, one beam provides a reference signal and the other a measuring signal. The blank (reference) is placed in the first beam and the sample in second. By referring intermittently or continuously to the reference beam when making measurements, errors that arise from fluctuations and drift in applied voltage, source
intensity detector response, amplifier gain and other irregularities, as well as, those errors that the blank is particularly designed to compensate, are largely eliminated. A monochromatic source splits into two identical beams using a rotating sector mirror which alternately passes and reflects the beam directed at it (in some spectrophotometers), while in some other cases a stationary splitting device is used, in such cases two detectors are required. Either the difference or the ratio of their outputs is determined, amplified and presented, while where splitting is achieved by chopper, detection can be performed by either dual detectors or a single detector. In recording spectrophotometer once a sample and a reference are in place and controls are set, it determines and records the absorption curve of sample over one or more spectral ranges. For recording R and T spectral curved over the range 400-900 nm glass slide was used as reference in the present investigations.

III. THEORETICAL STUDIES AND DISCUSSION

3.1 MAXWELL’S COUNTING FOR FLOPPY MODES & AVERAGE COORDINATION NUMBER

According to J. C. Phillips it may be valuable to consider the transitions between \( Z = 2.4 \) and 2.67 in the light of the constraint – counting argument originally proposed for amorphous covalent materials [5]. Phillips gave the mechanical-constraint counting algorithms to explain glass forming tendencies. The strongest covalent forces between nearest neighbours serve as Lagrangian (mechanical) constraints defining the elements of local structure (building blocks). Constraints associated with the weaker forces of more distant neighbours must be intrinsically broken leading to the absence of long-range order. The well known Phillips–Thorpe approach is based on comparing the number of atomic degrees of freedom with the number of inter-atomic force field constraints. If the number of degrees of freedom is greater than the number of constraints, the network is “floppy”; conversely, if the network becomes over-constrained, stressed-rigid structures will percolate throughout the entire network. According to Phillips, the tendency of glass formation would be maximum when the number of degrees of freedom exactly equals the number of constraints.

For the composition \( \text{Ge}_{10-x}\text{Se}_{90-x}\text{Sb}_x \) \((x = 0, 3, 6, 9, 12, 15, 18, 21, 24)\). The average coordination number \( Z \) was calculated by using the standard method [6].

\[
Z = \frac{aN_{Ge} + bN_{Se} + cN_{Sb}}{a + b + c}
\]

where \( a, b, \) and \( c \) are the atomic % of \( \text{Ge}, \text{Se}, \) and \( \text{Sb} \) respectively and \( N_{Ge}(4), N_{Se}(2), \) and \( N_{Sb}(3) \) are their respective coordination number [6]. It is clear from the figure 1 that values of \( Z \) increase from 2.22 to 2.42 with increase in concentration of \( \text{Sb} \) from 0 to 24.

3.2 MEAN BOND ENERGY

The properties of chalcogenide glasses are related to overall mean bond energy \( \langle E \rangle \) which is the average function of average coordination number, the types of bond and bond energy. The correlation was proposed by Tichy & Ticha [7, 8]. The overall mean bond energy for the system \( \text{Ge}_{10-x}\text{Se}_{90-x}\text{Sb}_x \) is given by

\[
\langle E \rangle = E_c + E_{rm}
\]

where \( E_c \) is overall contribution towards bonds and \( E_{rm} \) is contribution arising from weaker bonds that remains after strong bond have been maximized i.e. average bond energy per atom if the “remaining matrix”. For chalcogen rich system for \( R>1 \) where there are heteropolar bonds and chalcogen-chalcogen bonds

\[
E_c = 4aE_{Ge-Ge} + 3cE_{Sb-Se}
\]

and
The overall mean bond energy \(<E>\) for the glassy composition Ge_{10}Se_{90-x}Sb_{x} (x = 0, 3, 6, 9, 12, 15, 18, 21, 24) is found to increase with increasing Sb content. A graphical variation of mean bond energy with atomic % of Sb is shown in figure 1.

\[
E_{\text{mm}} = \frac{2b - 4a - 3c}{Z} E_{\text{Se-Se}}
\]

Figure 1: Variation in coordination number and overall mean bond energy with Sb atomic %.

3.3 GLASS TRANSITION TEMPERATURE

The glass transition temperature \((T_g)\), below which, super cooled liquid becomes glassy alloy has been predicted theoretically for the composition by using several methods proposed by earlier researchers. Tichy and Ticha proposed an impressive relation between glass transition temperature and mean bond energy given by \([9]\).

\[
T_g = 311\left(\langle E \rangle - 0.9\right)
\]

Figure 2: Variation in glass transition temperature with Sb atomic %.
The variation of $T_g$, corresponding to $<E>$ and with increase in Sb content is shown in figure 2, which is clearly depicting the rise in glass transition temperature with increasing the content of Sb from 0 to 24 atomic % for the present composition.

### 3.4 COHESIVE ENERGY

The cohesive energy of the system, defined as the stabilization energy of an infinitely large cluster of material per atom, has been calculated using the Chemical Bond Approach (CBA) [10]. According to CBA, atoms combine more favourably with atoms of different kind until all the available valences of the atom are filled. Bonds are always formed in the sequence of decreasing bond energies, which are assumed to be additive in nature. The heteropolar bond energies can be calculated by the relation [10].

$$E(A-B) = (E_{A-A} \times E_{B-B})^{0.5} + 30(\chi_A - \chi_B)^2$$

where $E(A-A)$ and $E(B-B)$ are the homopolar bond energies and $\chi_A$ and $\chi_B$ are corresponding electronegativities. The cohesive energy can be calculated using the relation [11].

$$CE = \sum_i C_i E_i$$

where $C_i$ is the distribution of the chemical bonds and $E_i$ is the energy associated with the corresponding bonds. It is evident from figure 3 that CE increases with increase in Sb from 0 to 24 atomic %. Se atoms are strongly bonded to the Ge atoms and fill the available valences of the Se and Sb atoms respectively. But, still there are some unsaturated Se atoms which appear as excess Se- Se bonds in the system. Thus, the overall mean bond energy of the system increases and hence the value of CE.

### 3.5 OPTICAL BAND GAP

The band gap values may be correlated to the bond strength of the system. Average single bond energy ($H/Z$) specifies the bond strength and it decreases with an increase in the Sb atomic %. This decreases the bond strength of the system. The band gap values have been calculated using Shimakawa’s relation as given by several investigators [11, 12].

$$E_g = AE_g(\text{Ge}) + BE_g(\text{Se}) + CE_g(\text{Sb})$$

where A, B, C are the volume fractions and $E_g(\text{Ge}) = 0.95$ eV, $E_g(\text{Se}) = 1.95$ and $E_g(\text{Sb}) = 0.101$ eV are the energy gaps of Ge, Se, and Sb respectively.
IV. OPTICAL STUDIES AND DISCUSSION

4.1 TRANSMISSION SPECTRA

Transmission spectra of Ge$_{10}$Se$_{90}$Sb$_{10}$ thin films shows that the transmission shifts towards longer wavelength with Sb addition to the ternary system. A red shift has been observed in interference free region of spectra shown in figure 4. In the region of weak and medium absorption where ($\alpha \neq 0$), the transmittance decreases mainly due to the effect of absorption coefficient ($\alpha$) and the refractive index ($n$). In the region of strong absorption, the transmittance decreases drastically, due to almost exclusively the influence of $\alpha$ and $n$ whose values can be estimated by extra plotting the values in other region.
4.2 REFRACTIVE INDEX

The variation in refractive index has been explained using polarizability of atoms. The refractive index (n) and polarizability are linked by the relation given by Lorentz – Lorentz [13]

\[
\frac{n^2 - 1}{n^2 + 2} = \frac{1}{3\varepsilon_0} \sum_i N_i \alpha_i
\]

where \( n \) is the refractive index of alloy, \( \alpha_i \) is the polarizability and \( \varepsilon_0 \) is the permittivity of the free space and \( N_i \) is the number of polarizable units per unit volume. As depicted from figure 5, the replacement of Se with Sb (different polarizable) leads to a variation in refractive index of the system [14]. The variation in the value of \( k \) with addition of Sb content indicates that loss of light changes due to scattering. A shift change evident from the Kramers–Kronig relation also supports the variation in refractive index [15, 16].
V. CONCLUSIONS

The average coordination number and overall mean bond energy increases and hence glass transition temperature increases because coordination no and heat of atomization of Sb are greater than that of Se. The cohesive energy increases slightly and energy band gap of the system decreases due to decrease contents of chalcogen Se and increasing Sb. The steadily shift change in transmission spectra and decrease in refractive index at higher wavelength makes these materials potential candidate for ultra high-band width signal processing and infrared optical sensors for medical applications.

REFERENCES


DOI: 10.15680/IJIRSET.2015.0401034  www.ijirset.com  18614